

NPN Triple Diffused Planar Silicon Transistor

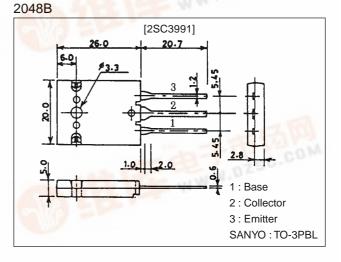


Features

- · High breakdown voltage, high reliability.
- · Fast switching speed ($t_f=0.1\mu s$ typ).
- · Wide ASO.
- · Adoption of MBIT process.

Package Dimensions

unit:mm



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		800	V
Collector-to-Emitter Voltage	VCEO		500	V
Emitter-to-Base Voltage	VEBO	111	7	V
Collector Current	ΙC		50	А
Collector Current (Pulse)	ICP	PW≤300µs, duty cycle≤10%	70	А
Base Current	Ι _Β	A LE W	14	А
Collector Dissipation	PC		3.5	W
		Tc=25°C	300	W
Junction Temperature	Tj	D Take	150	°C
Storage Temperature	Tstg	C.C.D.M.	-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Onit
Collector Cutoff Current	ICBO	V _{CB} =500V, I _E =0			10	μA
Emitter Cutoff Current	IEBO	V _{EB} =5V, I _C =0		235	10	μA
DC Current Gain	h _{FE} 1*	V _{CE} =5V, I _C =4.8A	15		50	20.0
	h _{FE} 2	V _{CE} =5V, I _C =24A	8	10.01		
Gain-Bandwidth Product	fT	V _{CE} =10V, I _C =4.8A	A4	18		MHz
Output Capacitance	Cob	V _{CB} =10V, f=1MHz		560		pF

*: The h_{FE}l of the 2SC3991 is classified as follows. When specifying the h_{FE}l rank, specify two ranks or more in principle.

15 L 30 20 M 40 30 N 50

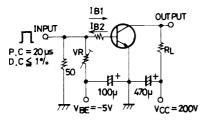
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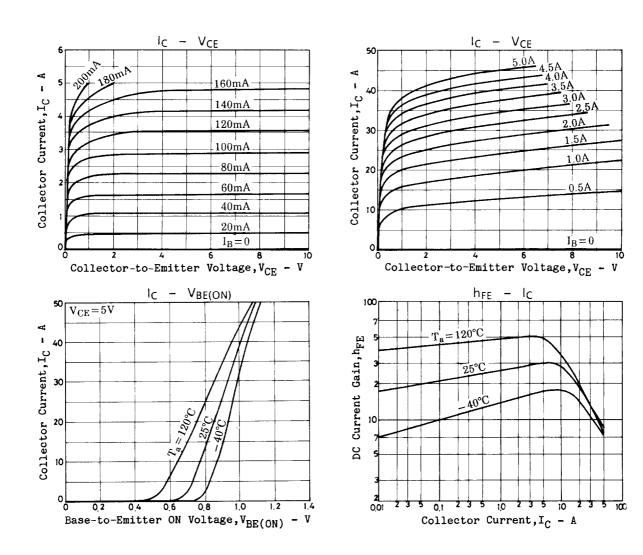
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Parameter	Symbol	Conditions		Ratings		
	Symbol		min	typ	max	Unit
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =24A, I _B =4.8A			1.0	V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =24A, I _B =4.8A			1.5	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =1mA, I _E =0	800			V
Collector-to-Emitter Breakdown Voltage	V _(BR) CEO	I _C =10mA, R _{BE} =∞	500			V
Emitter-to-Base Breakdown Voltage	V _{(BR)EBO}	I _E =1mA, I _C =0	7			V
Collector-to-Emitter Sustain Voltage	VCEX(sus)	I _C =15A, I _{B1} =–I _{B2} =–2A, L=100µH, clamped	500			V
Turn-ON Time	ton	V_{CC} =200V, 5I _{B1} =-2.5I _{B2} =I _C =26A, R _L =7.7 Ω			0.5	μs
Storage Time	tstg	V_{CC} =200V, 5I _{B1} =-2.5I _{B2} =I _C =26A, R _L =7.7 Ω			3.0	μs
Fall Time	t _f	V_{CC} =200V, 5I _{B1} =-2.5I _{B2} =I _C =26A, R _L =7.7 Ω			0.3	μs

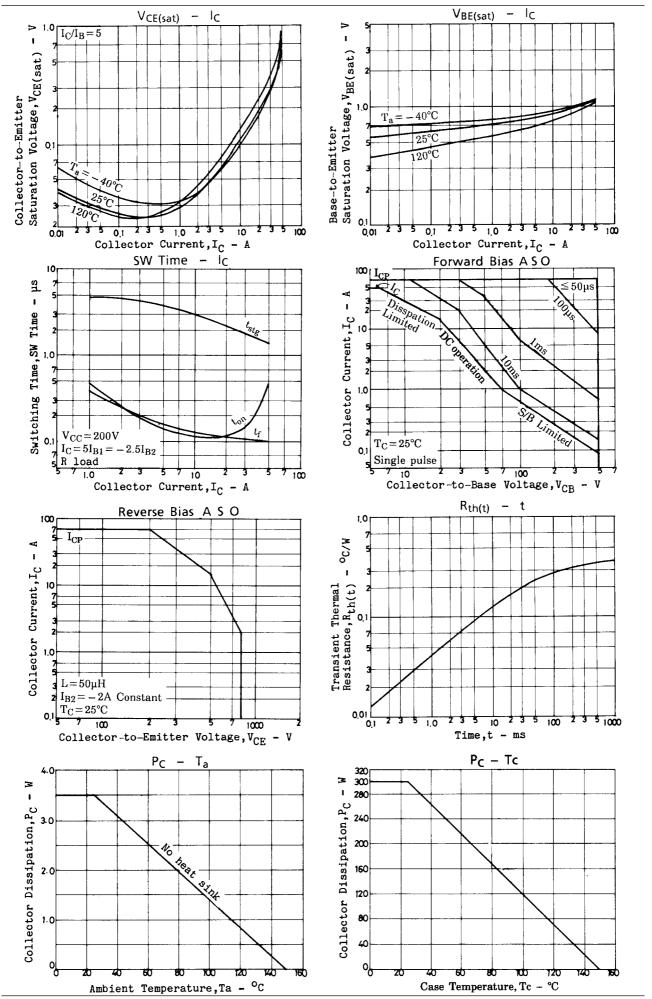
Switching Time Test Circuit



Unit (resistance : Ω , capacitance : F)



2SC3991



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